Dual Switching Diode

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Rating	Symbol	Max	Unit
Reverse Voltage	V _R	100	Vdc
Forward Current	IF	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T _A = 25°C	P _D	225	mW
Derated above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	555	°C/W
Total Device Dissipation, FR-4 Board (Note 2) T _A = 25°C	P _D	360	mW
Derated above 25°C		2.9	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	345	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

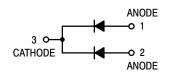
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad

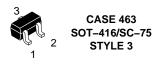


ON Semiconductor®

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MARKING DIAGRAM





A4 = Specific Device Code
M = Date Code
Device Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
BAV70TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVBAV70TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVBAV70TT3G	SOT-416 (Pb-Free)	10000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage (I _(BR) = 100 μAdc)	V _(BR)	100	-	Vdc
Reverse Voltage Leakage Current (Note 3) (V _R = 100 Vdc) (V _R = 50 Vdc)	I _R	- -	1.0 100	μAdc nAdc
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	_	1.5	pF
Forward Voltage $ \begin{aligned} &(I_F = 1.0 \text{ mAdc}) \\ &(I_F = 10 \text{ mAdc}) \\ &(I_F = 50 \text{ mAdc}) \\ &(I_F = 150 \text{ mAdc}) \end{aligned} $	V _F	- - - -	715 855 1000 1250	mVdc
Reverse Recovery Time (I _F = I _R = 10 mAdc, R _L = 100 Ω , I _{R(REC)} = 1.0 mAdc) (Figure 1)	t _{rr}	_	6.0	ns
Forward Recovery Voltage $(I_F = 10 \text{ mAdc}, t_r = 20 \text{ ns})$ (Figure 2)	V _{RF}	_	1.75	V

^{3.} For each individual diode while the second diode is unbiased.

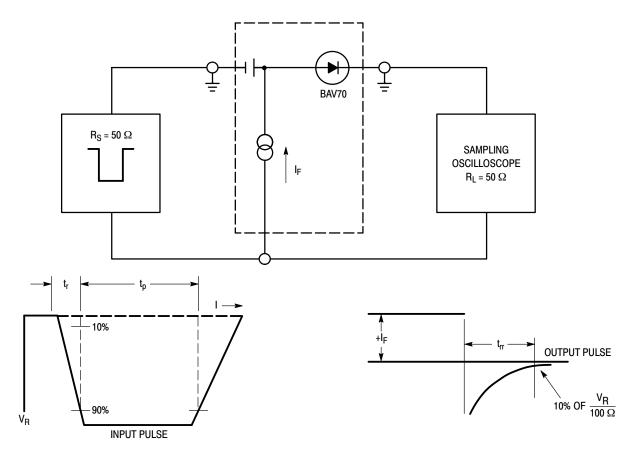
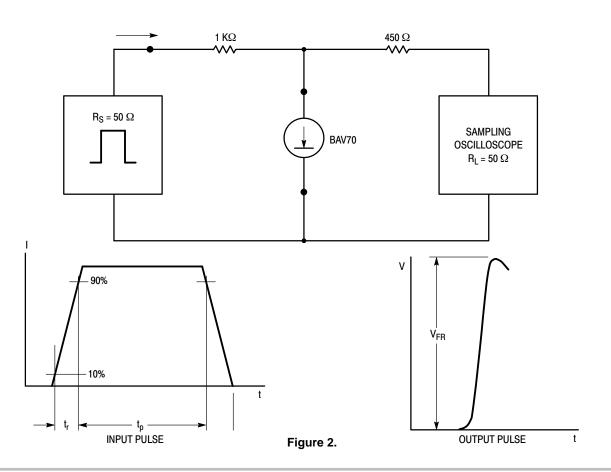
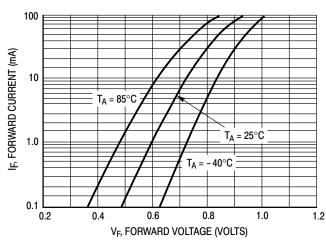


Figure 1. Recovery Time Equivalent Test Circuit





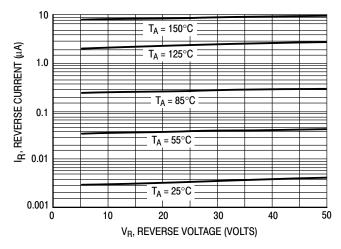


Figure 3. Forward Voltage

Figure 4. Leakage Current

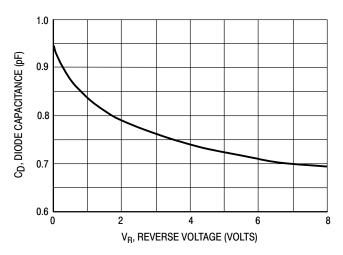


Figure 5. Capacitance

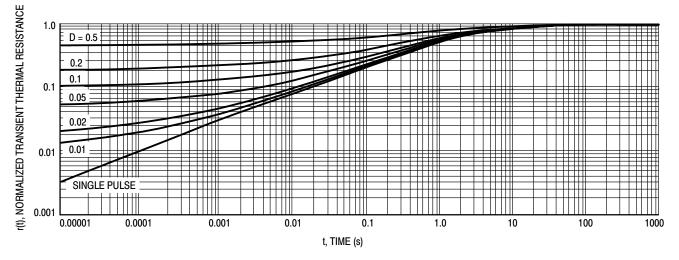


Figure 6. Normalized Thermal Response

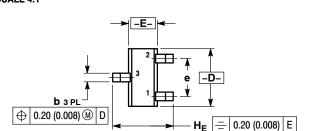
MECHANICAL CASE OUTLINE

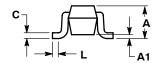




SC-75/SOT-416 CASE 463-01 ISSUE G

DATE 07 AUG 2015





STYLE 1: PIN 1. BASE 2. EMITTER

STYLE 4:

3. COLLECTOR

PIN 1. CATHODE 2. CATHODE 3. ANODE

STYLE 5: PIN 1. GATE 2. SOURCE

3. DRAIN

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

		MILLIMETERS			INCHES		
DII	И	MIN	NOM	MAX	MIN	NOM	MAX
Α		0.70	0.80	0.90	0.027	0.031	0.035
A	1	0.00	0.05	0.10	0.000	0.002	0.004
b		0.15	0.20	0.30	0.006	0.008	0.012
С		0.10	0.15	0.25	0.004	0.006	0.010
D		1.55	1.60	1.65	0.061	0.063	0.065
E		0.70	0.80	0.90	0.027	0.031	0.035
е		1.00 BSC			C	0.04 BSC)
L		0.10	0.15	0.20	0.004	0.006	0.008
HE	:	1.50	1.60	1.70	0.060	0.063	0.067

GENERIC MARKING DIAGRAM*

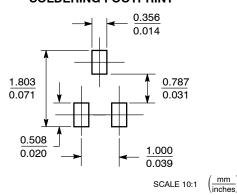


XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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